

Vishay General Semiconductor

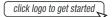
Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.57 \text{ V}$ at $I_F = 2.5 \text{ A}$





DESIGN SUPPORT TOOLS





PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5 A			
V_{RRM}	170 V			
I _{FSM}	80 A			
V _F at I _F = 5.0 A	0.65 V			
T _J max.	175 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

COMPLIANT HALOGEN

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

 Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 and M3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VB10170C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	170	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	10	^	
	per diode		5	— A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	80	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +175	°C	



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 2.5 A	T _A = 25 °C	V _F ⁽¹⁾	0.74	-	V	
	I _F = 5.0 A			0.84	1.03		
	I _F = 2.5 A	T _A = 125 °C		0.57	-		
	I _F = 5.0 A			0.65	0.74		
Reverse current per diode	V _R = 136 V	T _A = 25 °C	I _R ⁽²⁾	0.3	-	μA	
		T _A = 125 °C		0.9	-	mA	
	V _R = 170 V	T _A = 25 °C		-	90	μA	
		T _A = 125 °C		1.3	10	mA	

Notes

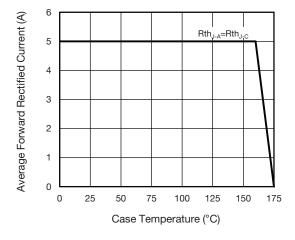
 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VB10170C	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	3.0	°C/W	
	per device		1.7	C/VV	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB10170C-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB10170C-E3/8W	1.38	8W	800/reel	Tape and reel	
TO-263AB	VB10170C-M3/I	1.38	I	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





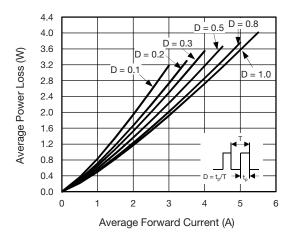


Fig. 2 - Forward Power Loss Characteristics Per Diode



www.vishay.com

Vishay General Semiconductor

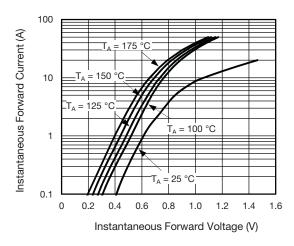


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

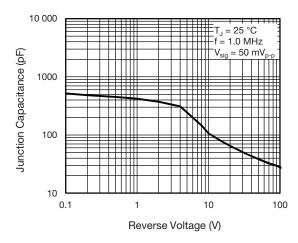


Fig. 5 - Typical Junction Capacitance Per Diode

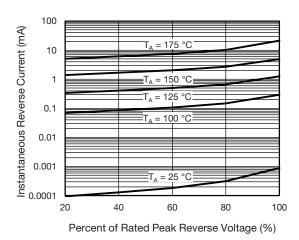


Fig. 4 - Typical Reverse Characteristics Per Diode

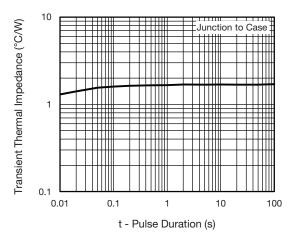
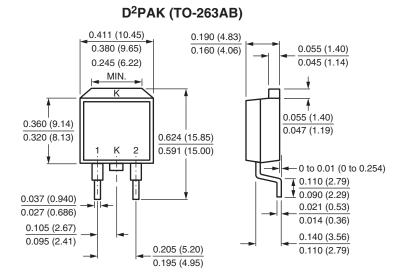
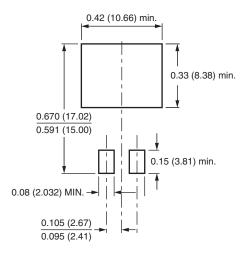


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.